



2SA1592/2SC4134

High-Voltage Switching Applications

Applications

- Power supplies, relay drivers, lamp drivers.

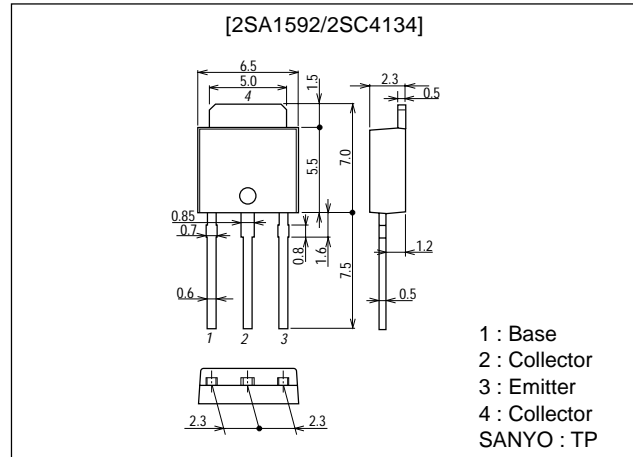
Features

- Adoption FBET, MBIT processes.
- High breakdown voltage and large current capacity.
- Fast switching speed.
- Small and slim package permitting 2SA1592/2SC4134-applied sets to be made more compact.

Package Dimensions

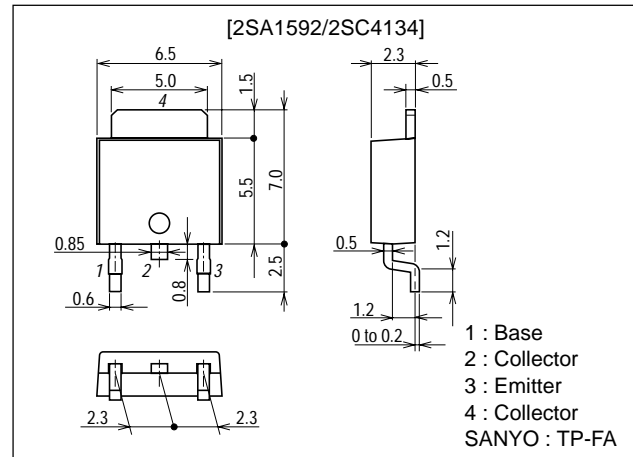
unit:mm

2045B



unit:mm

2044B



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2SA1592/2SC4134

() : 2SA1592

Specifications

Absolute Maximum Ratings at $T_a = 25^\circ\text{C}$

Parameter	Symbol	Conditions	Ratings	Unit
Collector-to-Base Voltage	V_{CB0}		(-)120	V
Collector-to-Emitter Voltage	V_{CEO}		(-)100	V
Emitter-to-Base Voltage	V_{EBO}		(-)6	V
Collector Current	I_C		(-)1	A
Collector Current (Pulse)	I_{CP}		(-)2	A
Collector Dissipation	P_C		0.8	W
		$T_c=25^\circ\text{C}$	10	W
Junction Temperature	T_j		150	$^\circ\text{C}$
Storage Temperature	T_{stg}		-55 to +150	$^\circ\text{C}$

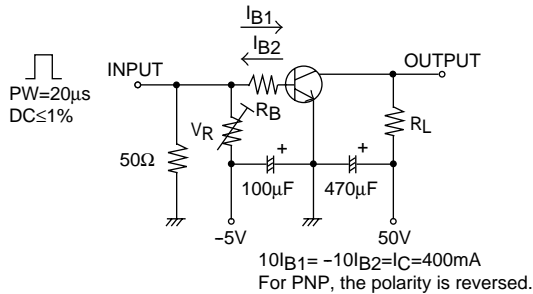
* : The 2SA1592/2SC4134 are classified by 100mA h_{FE} as follows :

Rank	R	S	T
h_{FE}	100 to 200	140 to 280	200 to 400

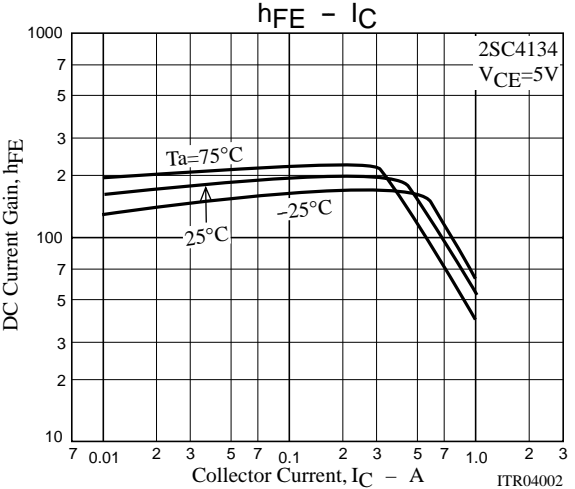
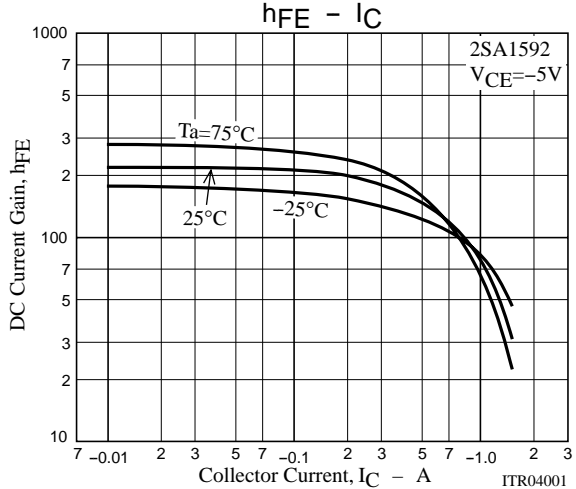
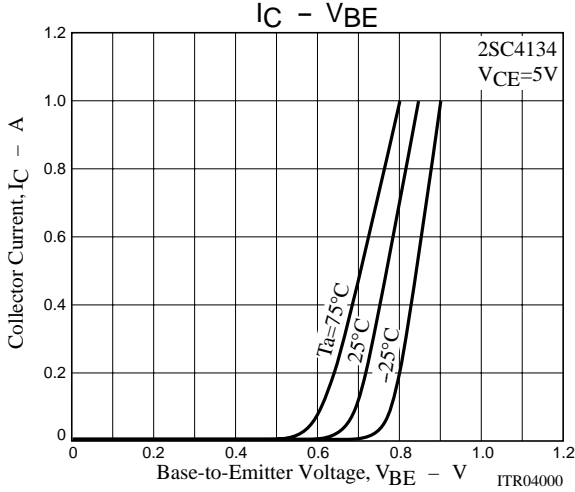
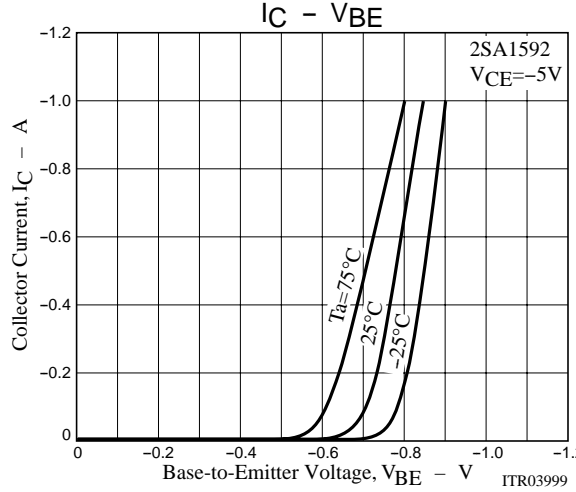
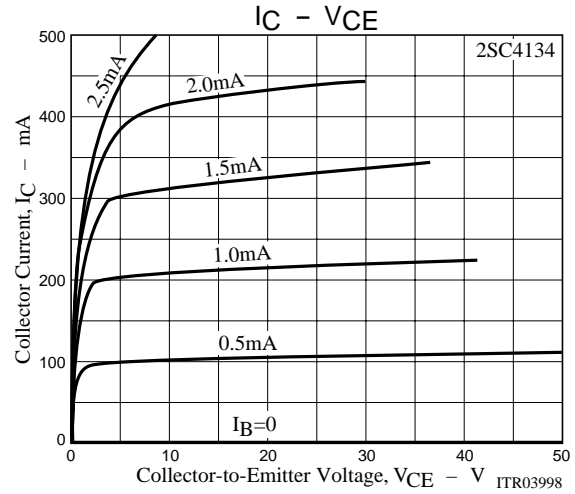
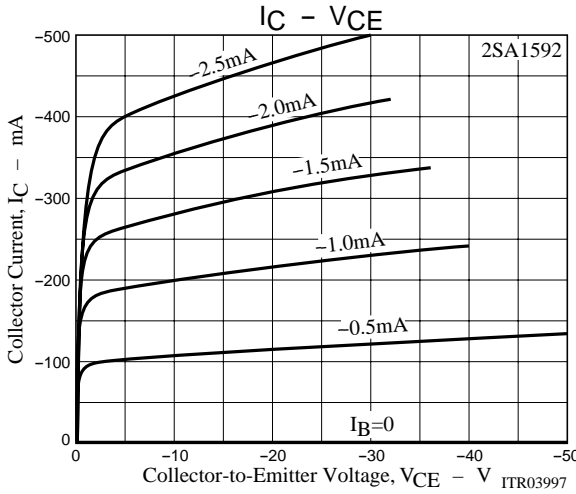
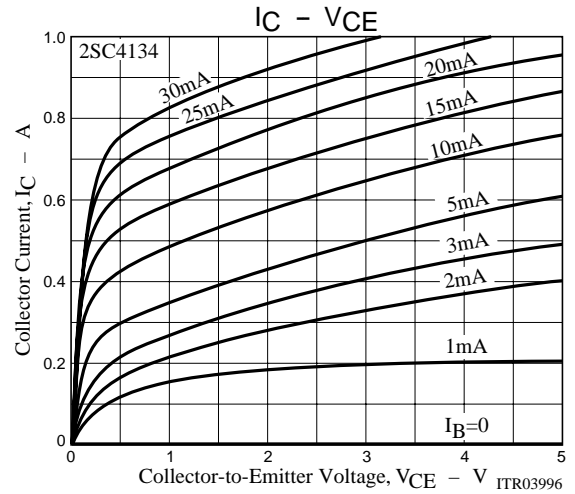
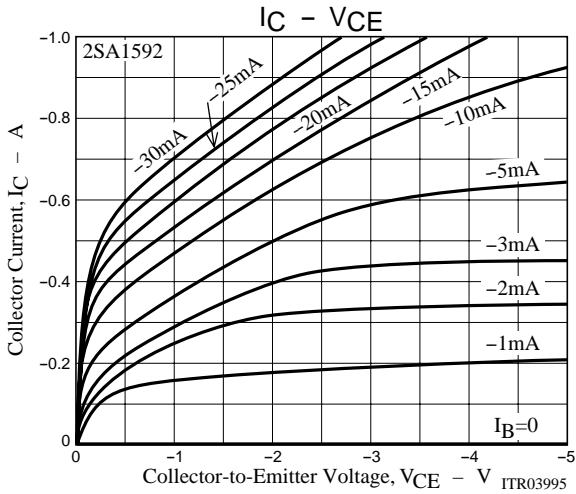
Electrical Characteristics at $T_a = 25^\circ\text{C}$

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Collector Cutoff Current	I_{CBO}	$V_{CB} = (-)100\text{V}, I_E = 0$			(-)100	nA
Emitter Cutoff Current	I_{EBO}	$V_{EB} = (-)4\text{V}, I_C = 0$			(-)100	nA
DC Current Gain	h_{FE}	$V_{CE} = (-)5\text{V}, I_C = (-)100\text{mA}$	100*		400*	
Gain-Bandwidth Product	f_T	$V_{CE} = (-)10\text{V}, I_C = (-)100\text{mA}$		120		MHz
Output Capacitance	C_{ob}	$V_{CB} = (-)10\text{V}, f = 1\text{MHz}$		8.5		pF
				(13)		pF
Collector-to-Emitter Saturation Voltage	$V_{CE(sat)}$	$I_C = (-)400\text{mA}, I_B = (-)40\text{mA}$		(-0.2)	(-0.6)	V
				0.1	0.4	V
Base-to-Emitter Saturation Voltage	$V_{BE(sat)}$	$I_C = (-)400\text{mA}, I_B = (-)40\text{mA}$		(-)0.85	(-)1.2	V
Collector-to-Base Breakdown Voltage	$V_{(BR)CBO}$	$I_C = (-)10\mu\text{A}, I_E = 0$	(-)120			V
Collector-to-Emitter Breakdown Voltage	$V_{(BR)CEO}$	$I_C = (-)1\text{mA}, R_{BE} = \infty$	(-)100			V
Emitter-to-Base Breakdown Voltage	$V_{(BR)EBO}$	$I_E = (-)10\mu\text{A}, I_C = 0$	(-)6			V
Turn-ON Time	t_{on}	See specified Test Circuit		(80)		ns
				80		ns
Storage Time	t_{stg}	See specified Test Circuit		(700)		ns
				850		ns
Fall Time	t_f	See specified Test Circuit		(40)		ns
				50		ns

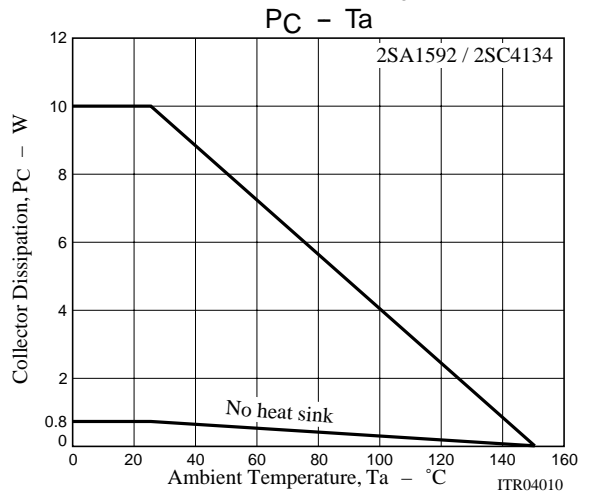
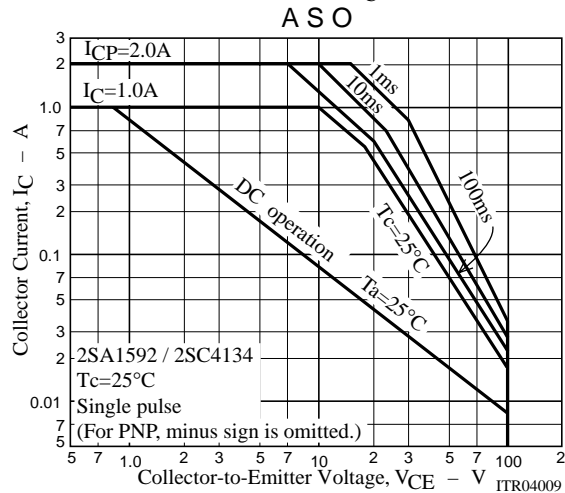
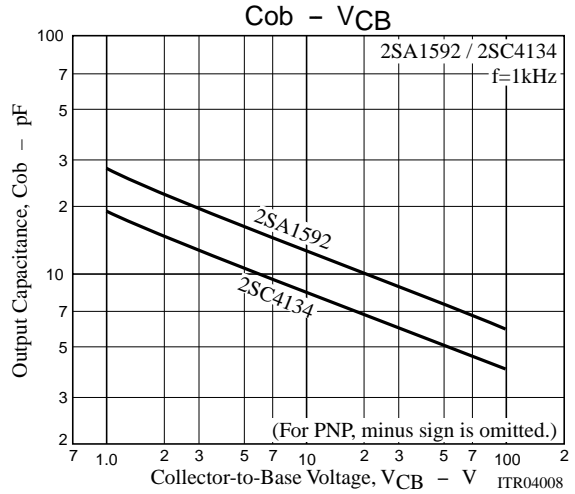
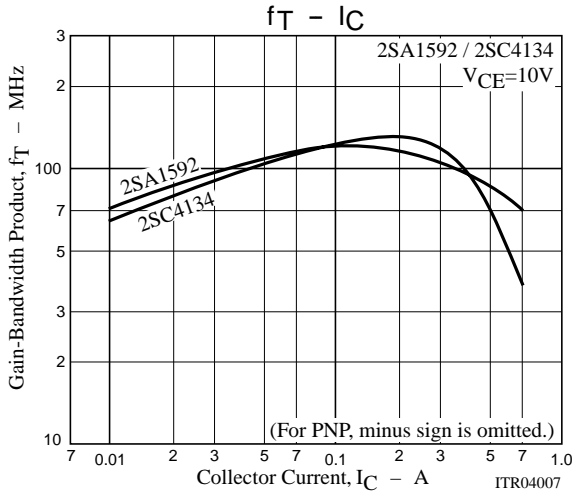
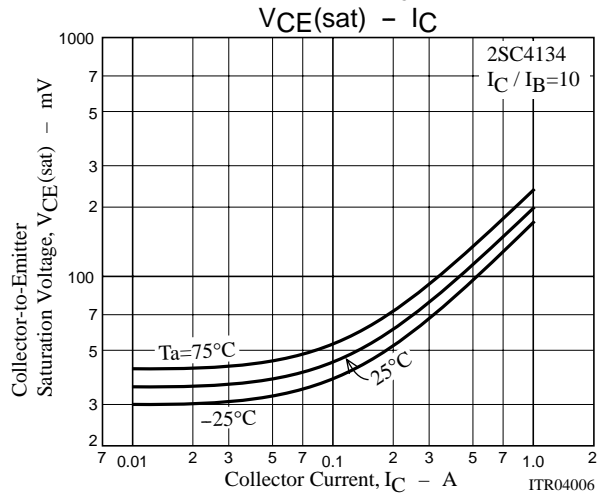
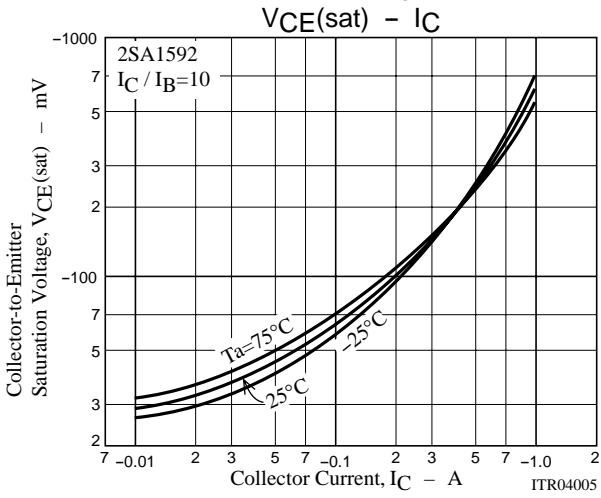
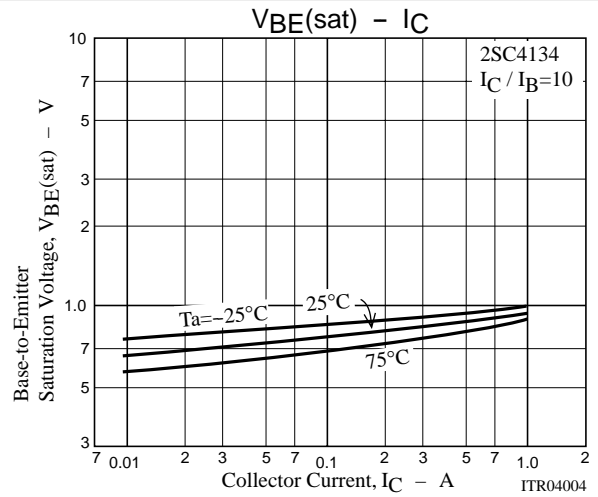
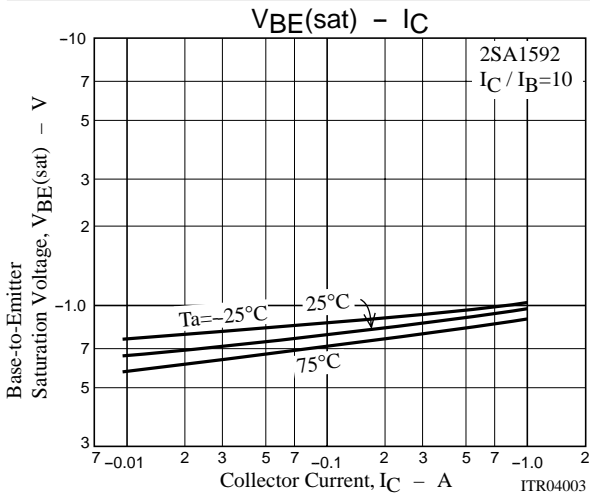
Switching Time Test Circuit



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